

Phonon-accurate machine-learning potentials from automated workflows

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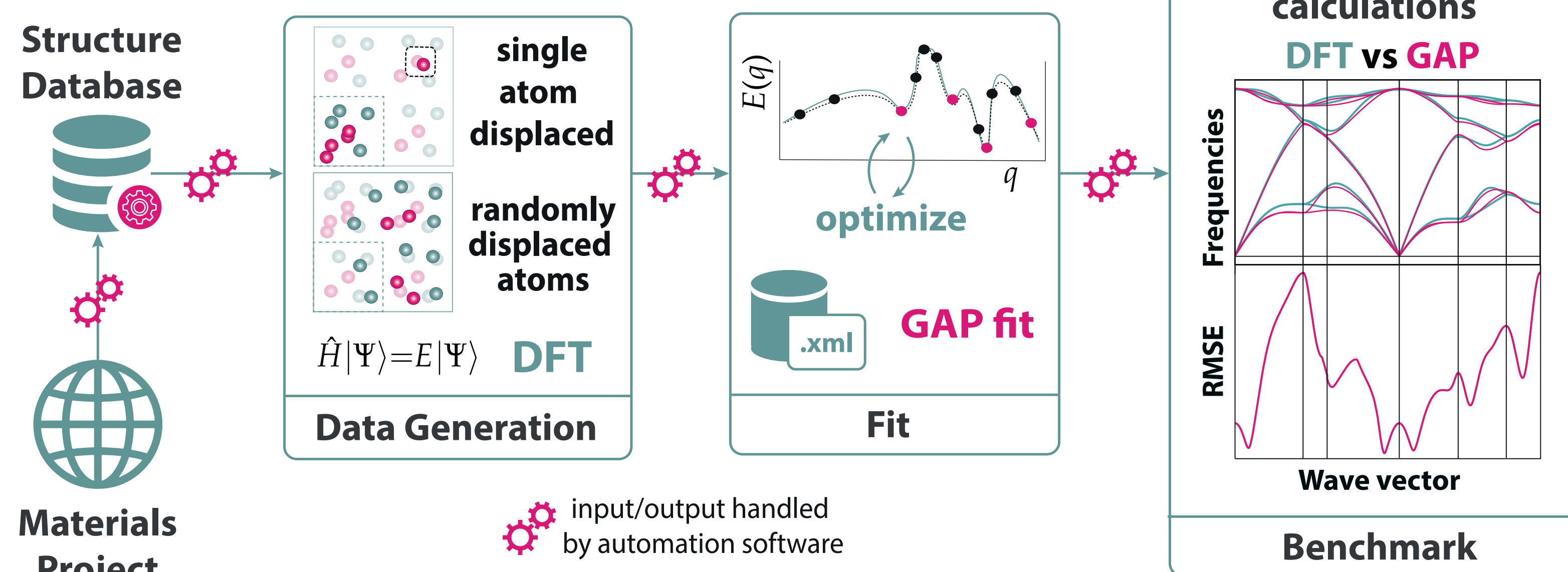
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Introduction

Data-driven materials design aims to predict and optimize material properties, such as **stability and thermal conductivity**, which are influenced by vibrational behavior. Approaches like DFT are computationally demanding and have limitations for phonon calculations. Machine learning-driven interatomic potentials (MLIP), like the **Gaussian approximation potential (GAP)**, offer a more efficient alternative.¹⁻⁸

We developed a Python workflow to **automate** MLIP generation using the Materials Project database.⁹ DFT computations, MLIP fitting and **benchmark** steps are automated.^{10,11} This approach accelerates phonon calculations and supports **testing** different data generation strategies and hyperparameters, and further **validation**¹² is planned. Our goal is to provide **open-source code** and share these potentials to enhance reproducibility and accessibility in computational chemistry.

Automated MLIP Generation



Results

The Python workflow was used to automatically construct a **Si database** (of single-atom and randomly displaced supercells) from 12 Si allotropes and perform SOAP-only GAP fits iterating through various combinations of convergence parameter and hyperparameter sets (n_{sparse} , SOAP delta). We present the results for MPIDs **mp-149**, **mp-1095269**, and **mp-971662**. All data is presented for the atomwise regularization parameter of 0.1.

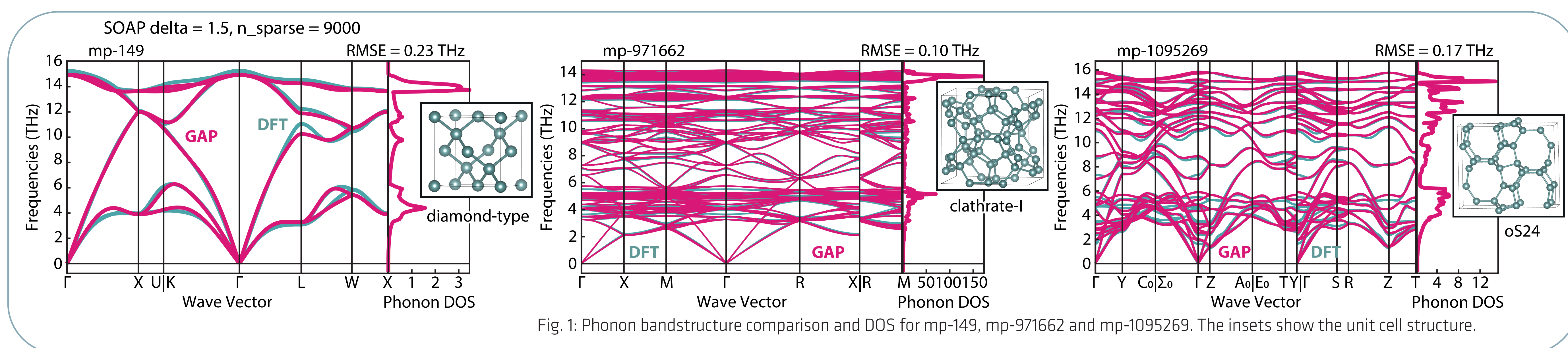


Fig. 1: Phonon bandstructure comparison and DOS for mp-149, mp-971662 and mp-1095269. The insets show the unit cell structure.

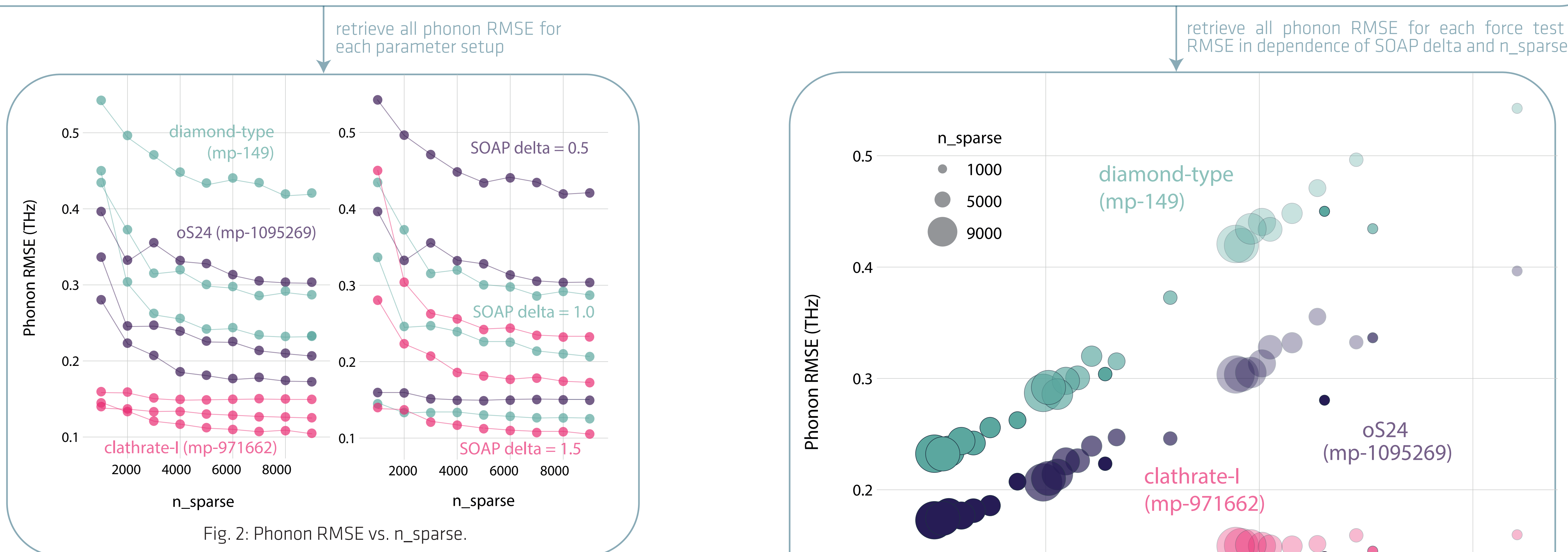


Fig. 2: Phonon RMSE vs. n_{sparse} .

Fig. 3: Phonon RMSE vs. force RMSE for the test data. The n_{sparse} values are used for resizing the data points and the SOAP delta (0.5, 1.0, 1.5) for different intensities.

Summary and Outlook

- > automated MLIP fit and benchmark successful
- > overall good correlation between different error metrics
- > quality of the fits and of the results improve a lot with an increasing n_{sparse} value
- > results for clathrate-I type Si are best overall
- > the best-performing parameter setup (SOAP delta = 1.5, n_{sparse} = 9000) generates comparably good results for the three shown Si allotropes

- > improve data generation and data quality [WIP]
- > more GAP fits with other atomwise regularization parameters [WIP] and repeat fit and data analysis for individual data types (single-atom/randomly displaced) [WIP]
- > check thermal properties (it is known from the literature⁷ that a too tight fit, i.e. a small atomwise regularization parameter, leads to instabilities in calculating thermal properties)
- > test other and more diverse chemical systems (e.g. Sb_2Se_3) [WIP]
- > test different MLIP architectures (frameworks are implemented in the Python workflow already)

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